Development Board EPC9004 Quick Start Guide

200 V Half-Bridge with Gate Drive, Using EPC2012



DESCRIPTIONwww.epc-co.com

The EPC9004 development board is a 200 V maximum device voltage, 2 A maximum output current, half bridge with onboard gate drives, featuring the EPC2012 enhancement mode (eGaN®) field effect transistor (FET). The purpose of this development board is to simplify the evaluation process of the EPC2012 eGaN FET by including all the critical components on a single board that can be easily connected into any existing converter.

The EPC9004 development board is 2" x 1.5" and contains not only two EPC2012 *eGaN* FET in a half bridge configuration using two

Texas Instruments UCC27611 gate drivers as well as supply and bypass capacitors. The board contains all critical components and layout for optimal switching performance. There are also various probe points to facilitate simple waveform measurement and efficiency calculation. A complete block diagram of the circuit is given in Figure 1.

For more information on the EPC2012 *eGaN* FET please refer to the datasheet available from EPC at www.epc-co.com. The datasheet should be read in conjunction with this quick start guide.

Table 1: Performance Summary (TA = 25°C)							
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS		
V _{DD}	Gate Drive Input Supply Range		7	12	V		
V _{IN}	Bus Input Voltage Range			150	V		
V _{out}	Switch Node Output Voltage			200	V		
I _{out}	Switch Node Output Current			2*	Α		
$V_{\scriptscriptstyle PWM}$	PWM Logic Input Voltage Threshold	Input 'High'	3.5	6	V		
		Input 'Low'	0	1.5	V		
	Minimum 'High' State Input Pulse Width	VPWM rise and fall time < 10ns	100		ns		
	Minimum 'Low' State Input Pulse Width	VPWM rise and fall time < 10ns	500#		ns		

^{*} Assumes inductive load, maximum current depends on die temperature – actual maximum current with be subject to switching frequency, bus voltage and thermals.

 $^{{\}tt\#\ Dependent\ on\ time\ needed\ to\ 'refresh'\ high\ side\ bootstrap\ supply\ voltage}.$

Quick Start Procedure

Development board EPC9004 is easy to set up to evaluate the performance of the EPC2012 *eGaN* FET. Refer to Figure 2 for proper connect and measurement setup and follow the procedure below:

- 1. With power off, connect the input power supply bus to $+V_{IN}$ (J5, J6) and ground / return to $-V_{IN}$ (J7, J8).
- 2. With power off, connect the switch node of the half bridge V_{OUT} (J3, J4) to your circuit as required.
- 3. With power off, connect the gate drive input to $+V_{DD}$ (J1, Pin-1) and ground return to $-V_{DD}$ (J1, Pin-2).
- 4. With power off, connect the input PWM control signal to PWM (J2, Pin-1) and ground return to any of the remaining J2 pins.
- 5. Turn on the gate drive supply make sure the supply is between 7 V and 12 V range.
- 6. Turn on the bus voltage to the required value (do not exceed the absolute maximum voltage of 200 V on V_{out}).
- 7. Turn on the controller / PWM input source and probe switching node to see switching operation.
- 8. Once operational, adjust the bus voltage and load PWM control within the operating range and observe the output switching behavior, efficiency and other parameters.
- 9. For shutdown, please follow steps in reverse.

NOTE. When measuring the high frequency content switch node (OUT), care must be taken to avoid long ground leads. Measure the switch node (OUT) by placing the oscilloscope probe tip through the large via on the switch node (designed for this purpose) and grounding the probe directly across the GND terminals provided. See Figure 3 for proper scope probe technique.

THERMAL CONSIDERATIONS

The EPC9004 development board showcases the EPC2012 eGaN FET. Although the electrical performance surpasses that for traditional Si devices, their relatively smaller size does magnify the thermal management requirements. The EPC9004 is intended for bench evaluation with low ambient temperature and convection cooling. The addition of heat-sinking and forced air cooling can significantly increase the current rating of these devices, but care must be taken to not exceed the absolute maximum die temperature of 125°C.

NOTE. The EPC9004 development board does not have any current or thermal protection on board.

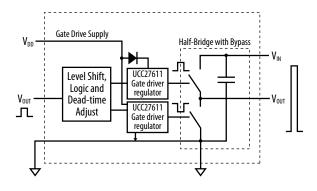


Figure 1: Block Diagram of EPC9004 Development Board

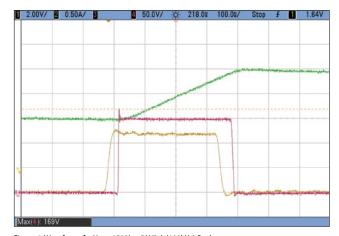


Figure 4: Waveforms for $V_{IN}=150\,V$ to $5\,V/2\,A$ (100kHz) Buck converter CH1: VPWM Input voltage – CH2: (I_{Out}) Switch node current – CH4: (V_{Out}) Switch node voltage

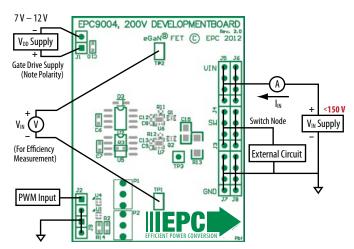


Figure 2: Proper Connection and Measurement Setup

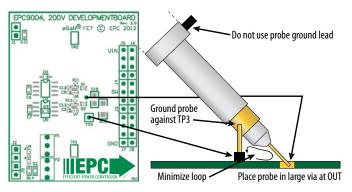
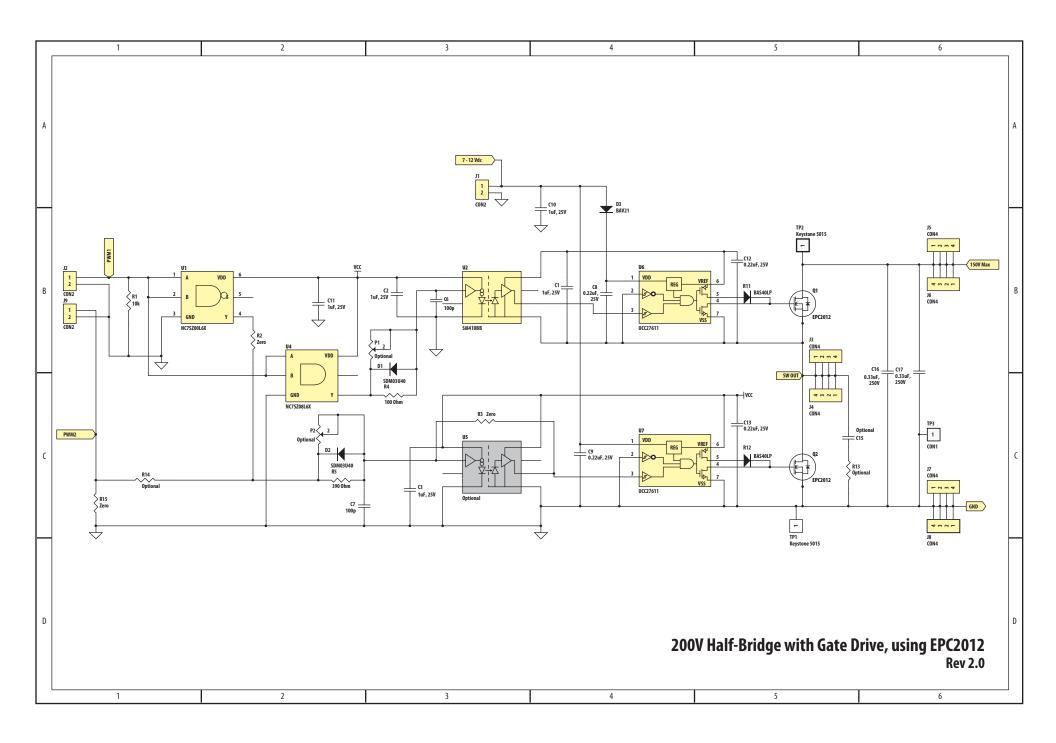


Figure 3: Proper Measurement of Switch Node – V_{OUT}

Table	2:	Bill	of N	Naterial
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Item	14.010 = 10.1110					
2 2 C6, C7 Capacitor, 100pF, 5%, 50V, NP0 TDK, C1608C0G1H101J 3 3 C16, C17 Capacitor, 0.33uF, 10%, 250V, X7R TDK, C4532X7R2E334M 4 4 C8, C9, C12, C13 Capacitor, 0.22uF, 10%, 16V, X7R TDK, C1005X7R1C224K 5 2 D1, D2 Schottky Diode, 30V Diodes Inc., SDM03U40-7 6 1 D3 Diode, 200V Diodes Inc., SDM03U40-7 7 1 J1 Connector 2pins of Tyco, 4-103185-0 8 1 J2 Connector 4pins of Tyco, 4-103185-0 9 1 J3, J4, J5, J6, J7, J8 Connector FCI, 68602-224HLF 10 2 Q1, Q2 eGANFET EPC, EPC2012 11 1 R1 Resistor, 10.0K, 5%, 1/8W Stackpole, RMCF0603FT10K0 12 3 R2, R3, R15 Resistor, 0 Ohm, 1/8W Stackpole, RMCF0603FT10K0 13 2 R11, R12 Diode, 40V Diodes Inc., BAS40LP-7 14 1 R4 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603FT10	ltem	Qty	Reference	Part Description	Manufacturer / Part #	
3 3 C16, C17 Capacitor, 0.33uF, 10%, 250V, X7R TDK, C4532X7R2E334M 4 4 C8, C9, C12, C13 Capacitor, 0.22uF, 10%, 16V, X7R TDK, C1005X7R1C224K 5 2 D1, D2 Schottky Diode, 30V Diodes Inc., SDM03U40-7 6 1 D3 Diode, 200V Diodes Inc., BAV21W5-7-F 7 1 J1 Connector 2pins of Tyco, 4-103185-0 8 1 J2 Connector 4pins of Tyco, 4-103185-0 9 1 J3, J4, J5, J6, J7, J8 Connector FCI, 68602-224HLF 10 2 Q1, Q2 eGaN FET EPC, EPC2012 11 1 R1 Resistor, 100, K, 5%, 1/8W Stackpole, RMCF0603FT10K0 12 3 R2, R3, R15 Resistor, 0 Ohm, 1/8W Stackpole, RMCF0603FT10K0 13 2 R11, R12 Diode, 40V Diodes Inc., BAS40LP-7 14 1 R4 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603FT100R 15 1 R5 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603F	1	4	C2, C3, C10, C11	Capacitor, 1uF, 10%, 25V, X5R	Murata, GRM188R61E105KA12D	
4 4 C8, C9, C12, C13 Capacitor, 0.22uf, 10%, 16V, X7R TDK, C1005X7R1C224K 5 2 D1, D2 Schottky Diode, 30V Diodes Inc., SDM03U40-7 6 1 D3 Diode, 200V Diodes Inc., BAV21W5-7-F 7 1 J1 Connector 2pins of Tyco, 4-103185-0 8 1 J2 Connector 4pins of Tyco, 4-103185-0 9 1 J3, J4, J5, J6, J7, J8 Connector FCI, 68602-224HLF 10 2 Q1, Q2 eGaN FET EPC, EPC2012 11 1 R1 Resistor, 10.0K, 5%, 1/8W Stackpole, RMCF0603FT10K0 12 3 R2, R3, R15 Resistor, 0 Ohm, 1/8W Stackpole, RMCF0603FT00R0 13 2 R11, R12 Diode, 40V Diodes Inc.,BAS40LP-7 14 1 R4 Resistor, 100 Ohm, 1%, 1/8W Stackpole, RMCF0603FT100R 15 1 R5 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603FT390R 16 2 TP1, TP2 Test Point Keystone Elect, 5015	2	2	C6, C7	Capacitor, 100pF, 5%, 50V, NP0	TDK, C1608C0G1H101J	
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8 1 J2 Connector 4pins of Tyco, 4-103185-0 9 1 J3, J4, J5, J6, J7, J8 Connector FCI, 68602-224HLF 10 2 Q1, Q2 eGaNFET EPC, EPC2012 11 1 R1 Resistor, 10.0K, 5%, 1/8W Stackpole, RMCF0603FT10K0 12 3 R2, R3, R15 Resistor, 0 Ohm, 1/8W Stackpole, RMCF0603FT10R0 13 2 R11, R12 Diode, 40V Diodes Inc.,BAS40LP-7 14 1 R4 Resistor, 100 Ohm, 1%, 1/8W Stackpole, RMCF0603FT100R 15 1 R5 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603FT300R 16 2 TP1, TP2 Test Point Keystone Elect, 5015 17 1 TP3 Connector 1/40th of Tyco, 4-103185-0 18 1 U1 LC., Logic Fairchild, NC7SZ00L6X 19 1 U2 LC., Isolator Silicon Laboratories, Si8410BB 20 1 U4 LC., Gate driver Texas Instruments, UCC27611 22 <td>6</td> <td>1</td> <td>D3</td> <td>Diode, 200V</td> <td>Diodes Inc.,BAV21WS-7-F</td>	6	1	D3	Diode, 200V	Diodes Inc.,BAV21WS-7-F	
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10 2 Q1, Q2 eGaNFET EPC, EPC2012 11	8	1	J2	Connector	4pins of Tyco, 4-103185-0	
11 1 R1 Resistor, 10.0K, 5%, 1/8W Stackpole, RMCF0603FT10K0 12 3 R2, R3, R15 Resistor, 0 Ohm, 1/8W Stackpole, RMCF0603FT00R0 13 2 R11, R12 Diode, 40V Diodes Inc.,BAS40LP-7 14 1 R4 Resistor, 100 Ohm, 1%, 1/8W Stackpole, RMCF0603FT100R 15 1 R5 Resistor, 390 Ohm, 1%, 1/8W Stackpole, RMCF0603FT390R 16 2 TP1,TP2 Test Point Keystone Elect, 5015 17 1 TP3 Connector 1/40th of Tyco, 4-103185-0 18 1 U1 I.C., Logic Fairchild, NC7SZ00L6X 19 1 U2 I.C., Isolator Silicon Laboratories, Si8410BB 20 1 U4 I.C., Logic Fairchild, NC7SZ08L6X 21 2 U6, U7 I.C., Gate driver Texas Instruments, UCC27611 22 0 C1, C15 Optional capacitor 23 0 P1, P2 Optional Potentiometer 24 0 R13, R14	9	1	J3, J4, J5, J6, J7, J8	Connector	FCI, 68602-224HLF	
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17 1 TP3 Connector 1/40th of Tyco, 4-103185-0 18 1 U1 I.C., Logic Fairchild, NC7SZ00L6X 19 1 U2 I.C., Isolator Silicon Laboratories, Si8410BB 20 1 U4 I.C., Logic Fairchild, NC7SZ08L6X 21 2 U6, U7 I.C., Gate driver Texas Instruments, UCC27611 22 0 C1, C15 Optional capacitor 23 0 P1, P2 Optional Potentiometer 24 0 R13, R14 Optional resistor	15	1	R5	Resistor, 390 Ohm, 1%, 1/8W	Stackpole, RMCF0603FT390R	
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22 0 C1, C15 Optional capacitor 23 0 P1, P2 Optional Potentiometer 24 0 R13, R14 Optional resistor	20	1	U4	I.C., Logic	Fairchild, NC7SZ08L6X	
23 0 P1, P2 Optional Potentiometer 24 0 R13, R14 Optional resistor	21	2	U6, U7	I.C., Gate driver	Texas Instruments, UCC27611	
24 0 R13, R14 Optional resistor	22	0	C1, C15	Optional capacitor		
	23	0	P1, P2	Optional Potentiometer		
25 0 U5 Optional I.C.	24	0	R13, R14	Optional resistor		
	25	0	U5	Optional I.C.		



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